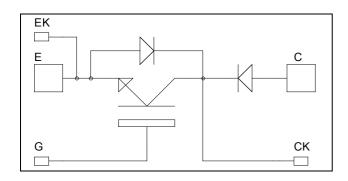


Single Switch with Series diodes NPT IGBT Power Module

 $V_{CES} = 1200V$ $I_{C} = 300A$ @ Tc = 80°C



Application

• Zero Current Switching resonant mode

Features

- Non Punch Through (NPT) FAST IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration



- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- Low profile
- RoHS compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
I_{C}	Continuous Collector Current	$T_c = 25^{\circ}C$	400	
	Continuous Conector Current	$T_c = 80^{\circ}C$	300	A
I_{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	600	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	1780	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	600A @ 1200V	

TAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

1 - 6



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
ī	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25$ °C			500	^
I_{CES}	Zero Gate voltage Collector Current	$V_{CE} = 1200V$	$T_j = 125$ °C			750	μΑ
V _{CE(sat)}	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		3.3	3.9	V
		$I_C = 300A$ $T_j = 125$	$T_j = 125$ °C		4		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 12mA$		4.5		6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = \pm 20V, V_{CE} = 0V$				±1	μA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
C_{ies}	Input Capacitance	$\begin{aligned} V_{GE} &= 0V \\ V_{CE} &= 25V \\ f &= 1MHz \end{aligned}$			21		
C_{oes}	Output Capacitance				2.9		nF
C_{res}	Reverse Transfer Capacitance				1.52		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			120		
$T_{\rm r}$	Rise Time	$V_{GE} = 15V$			50		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 300A$			310		ns
T_{f}	Fall Time	$R_G = 3\Omega$		30			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 600V$ $I_{C} = 300A$ $R_{G} = 3\Omega$			130		ns
$T_{\rm r}$	Rise Time				60		
$T_{d(off)}$	Turn-off Delay Time				360		
$T_{\rm f}$	Fall Time				40		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		25		Т
E_{off}	Turn-off Switching Energy	$I_C = 300A$ $R_G = 3\Omega$	$T_j = 125$ °C		15		mJ

Diode ratings and characteristics

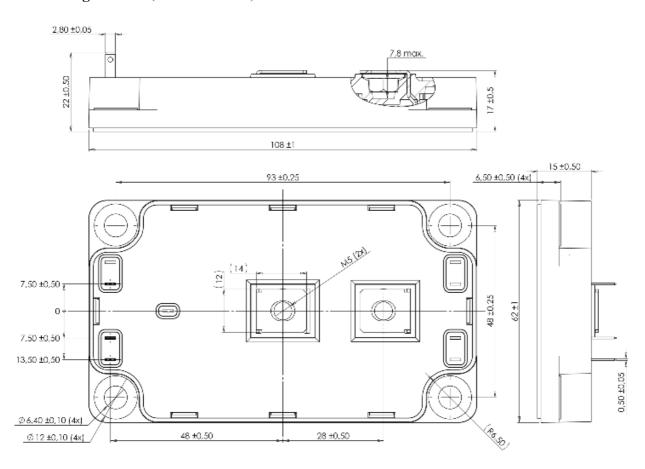
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_j = 25$ °C			250	μA
			$T_j = 125$ °C			500	μΑ
I_F	DC Forward Current		$Tc = 80^{\circ}C$		300		A
V_{F}	Diode Forward Voltage	$I_F = 300A$	$T_i = 25^{\circ}C$		2.1		V
V F			$T_{i} = 125^{\circ}C$		1.9		
t _{rr}	Reverse Recovery Time	$I_F = 300A$ $V_R = 600V$ $di/dt = 4500A/\mu s$	$T_j = 25^{\circ}C$		120		ns
			$T_j = 125$ °C		210		
Q _{rr}	Reverse Recovery Charge		$T_j = 25$ °C		22		μC
			$T_{j} = 125^{\circ}C$		43		μ
Er	Reverse Recovery Energy		$T_j = 25$ °C		7		mJ
			$T_i = 125^{\circ}C$		15		1113



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	L Junction to Case Thermal Resistance		IGBT			0.07	°C/W
TthJC			Diode			0.12	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	
Wt	Package Weight					300	g

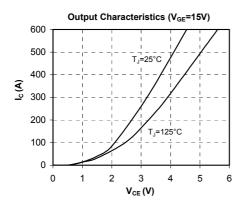
SP6 Package outline (dimensions in mm)

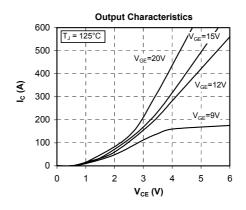


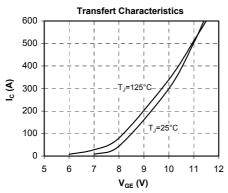
 $See \ application \ note \ APT0601 - Mounting \ Instructions \ for \ SP6 \ Power \ Modules \ on \ www.microsemi.com$

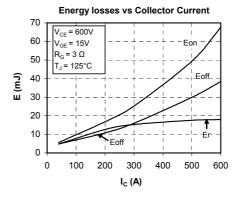
Typical Performance Curve

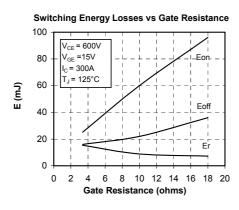


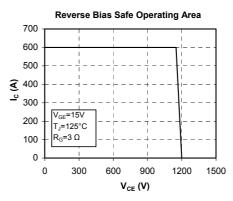


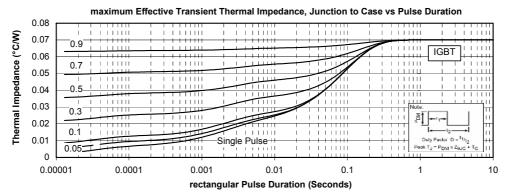




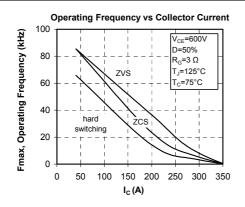


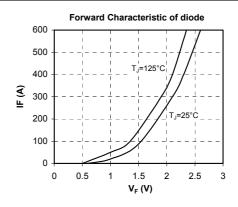


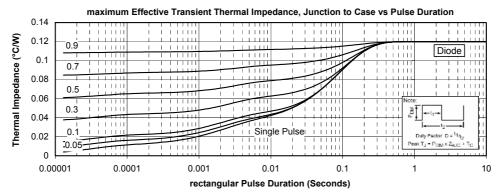














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